1N5059, 1N5060, 1N5061, 1N5062

axial-leaded

**Vishay Semiconductors** 

glass

# **Standard Avalanche Sinterglass Diode**

**FEATURES** 

Hermetically

Low reverse current

**APPLICATIONS** 

envelope

Glass passivated junction

High surge current loading

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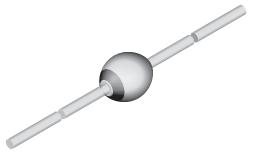
Rectification diode, general purpose

• Material categorization:

sealed

for definitions of compliance please see

· Controlled avalanche characteristics



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#### **DESIGN SUPPORT TOOLS**



### **MECHANICAL DATA**

Case: SOD-57

Terminals: plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

#### Mounting position: any

Weight: approx. 369 mg

ORDERING INFORMATION (Example)					
DEVICE NAME	ORDERING CODE	RDERING CODE TAPED UNITS MINIMUM ORDE			
1N5062	1N5062TR	5000 per 10" tape and reel	25 000		
1N5062	1N5062TAP	5000 per ammopack	25 000		

PARTS TABLE					
PART	TYPE DIFFERENTIATION	PACKAGE			
1N5059	$V_{R} = 200 \text{ V}; \text{ I}_{F(AV)} = 2 \text{ A}$	SOD-57			
1N5060	$V_{R} = 400 \text{ V}; \text{ I}_{F(AV)} = 2 \text{ A}$	SOD-57			
1N5061	$V_{R} = 600 \text{ V}; \text{ I}_{F(AV)} = 2 \text{ A}$	SOD-57			
1N5062	V <sub>R</sub> = 800 V; I <sub>F(AV)</sub> = 2 A	SOD-57			

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
	e See electrical characteristics	1N5059	$V_{R} = V_{RRM}$	200	V	
Reverse voltage = repetitive peak reverse voltage		1N5060	$V_{R} = V_{RRM}$	400	V	
Reverse voltage = repetitive peak reverse voltag		1N5061	$V_{R} = V_{RRM}$	600	V	
		1N5062	$V_{R} = V_{RRM}$	800	V	
Peak forward surge current	$t_p = 10$ ms, half sine wave		I <sub>FSM</sub>	50	А	
Average forward current	$T_{thJA} = 45$ K/W, $T_{amb} = 50$ °C		I <sub>F(AV)</sub>	2	А	
Average for ward current	$T_{thJA}$ = 100 K/W, $T_{amb}$ = 75 °C		I <sub>F(AV)</sub>	0.8	А	
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	$I_{(BR)R} = 1$ A, inductive load		E <sub>R</sub>	20	mJ	
Junction and storage temperature range			$T_j = T_{stg}$	-55 to +175	°C	

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<b>MAXIMUM THERMAL RESISTANCE</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Junction ambient	Lead length I = 10 mm, $T_L$ = constant	R <sub>thJA</sub>	45	K/W	
	On PC board with spacing 25 mm	R <sub>thJA</sub>	100	K/W	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX	UNIT
Forward voltage	I <sub>F</sub> = 1 A		V <sub>F</sub>	-	-	1	V
	I <sub>F</sub> = 2.5 A		V <sub>F</sub>	-	-	1.15	V
Reverse current	$V_{R} = V_{RRM}$		I <sub>R</sub>	-	-	1	μA
	$V_{R} = V_{RRM}, T_{j} = 100 ^{\circ}\text{C}$		I <sub>R</sub>	-	-	10	μA
	$V_{R} = V_{RRM}, T_{j} = 150 \text{ °C}$		I <sub>R</sub>	-	-	100	μA
	I <sub>R</sub> = 100 μA	1N5059	V <sub>(BR)R</sub>	225	-	1600	V
Broakdown voltago		1N5060	V <sub>(BR)R</sub>	450	-	1600	V
Breakdown voltage		1N5061	V <sub>(BR)R</sub>	650	-	1600	V
		1N5062	V <sub>(BR)R</sub>	900	-	1600	V
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		CD	-	40	-	pF
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, i_R = 0.25 \text{ A}$		t <sub>rr</sub>	-	-	4	μs

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

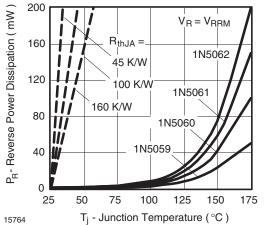
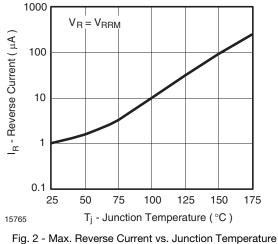


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature





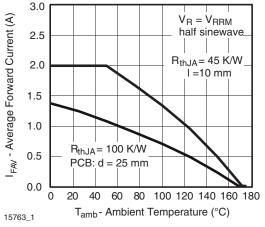
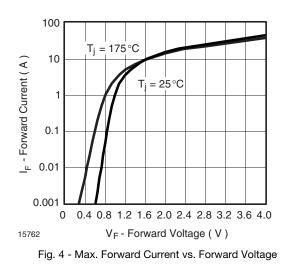


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature



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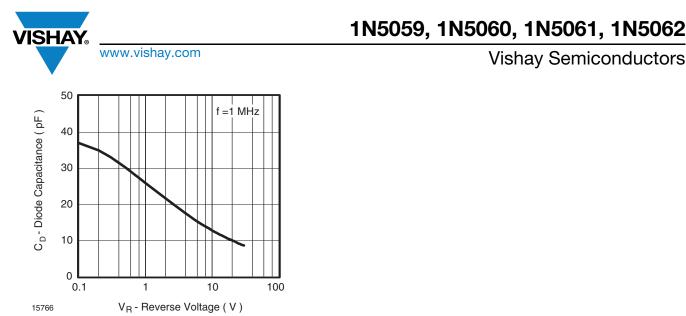
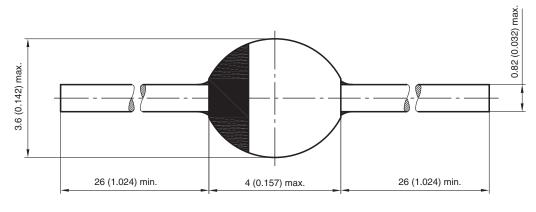


Fig. 5 - Diode Capacitance vs. Reverse Voltage

### PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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